

ACST10

Transient protected AC power switch

Features

- Triac with overvoltage crowbar technology
- Low I_{GT} (<10 mA) or high immunity (I_{GT}<35 mA) version
- High noise immunity: static dV/dt > 2000 V/µs

Benefits

- Enables equipment to meet IEC 61000-4-5
- High off-state reliability with planar technology
- Need no external over voltage protection
- Reduces the power passive component count
- High immunity against fast transients described in IEC 61000-4-4 standards

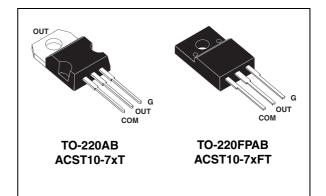
Applications

- AC mains static switching in appliance and industrial control systems
- Drive of medium power AC loads like:
 - Universal drum motor of washing machine
 - Compressor for fridge or air conditioner

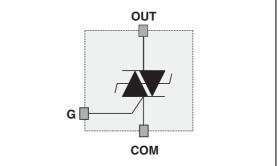
Description

The **ACST10 series** belongs to the ACS/ACST family built with the ASD (application specific discrete) technology. This high performance device is adapted to home appliances or industrial systems, and drives loads up to 10 A.

This ACST10 switch embeds a TRIAC structure and a high voltage clamping device able to absorb the inductive turn-off energy and withstand line transients such as those described in the IEC 61000-4-5 standards. The ACST10-7S needs only low gate current to be activated ($I_{GT} < 10$ mA) and still shows a high noise immunity complying with IEC standards such as IEC 61000-4-4 (Fast transient burst test). The ACST10-7C offers an extremely high static dV/dt immunity of 2 kV/µs minimum.







Symbol	Value	Unit
I _{T(RMS)}	10	A
V _{DRM} /V _{RRM}	700	V
I _{GT}	10 or 35	mA

1 Characteristics

Symbol	Paramete		Value	Unit	
1	On-state rms current (full sine wave)	TO-220AB T _c = 105 °C		10	А
I _{T(RMS)}	(RMS) Off-state fins current (fun sine wave)	TO-220FPAB	T _{amb} = 84 °C	10	А
1.	Non repetitive surge peak on-state current	F = 60 Hz	t _p = 16.7 ms	105	А
ITSM	T_j initial = 25 °C, (full cycle sine wave)	F = 50 Hz	t _p = 20 ms	100	А
l ² t	I ² t for fuse selection		t _p = 10 ms	66	A ² s
dl/dt	Critical rate of rise on-state current $I_G = 2 \times I_{GT}$, (t _r ≤ 100 ns)	F = 120 Hz	T _j = 125 °C	100	A/µs
V _{PP}	Non repetitive line peak pulse voltage ⁽¹⁾		T _j = 25 °C	2	kV
P _{G(AV)}	Average gate power dissipation T _j =		T _j = 125 °C	0.1	W
P _{GM}	Peak gate power dissipation ($t_p = 20 \ \mu s$) $T_j =$		T _j = 125 °C	10	W
I _{GM}	Peak gate current ($t_p = 20 \ \mu s$)		T _j = 125 °C	1	А
T _{stg}	Storage temperature range			-40 to +150	°C
Тj	Operating junction temperature range			-40 to +125	°C

Table 2. Absolute ratings (limiting values)

1. According to test described in IEC 61000-4-5 standard and Figure 17

Table 3. Electrical characteristics

Symbol	Test conditions	Quadrant	т		Va	lue	Unit
Symbol		Quadrant	Тј		ACST10-7Sx	ACST10-7Cx	Onit
I _{GT} ⁽¹⁾	V_{OUT} = 12 V, R _L = 33 Ω	- -	25 °C	MAX.	10	35	mA
V _{GT}	V_{OUT} = 12 V, R _L = 33 Ω	- -	25 °C	MAX.	1.0		V
V_{GD}	$V_{OUT} = V_{DRM}, R_L = 3.3 \Omega$	- -	125 °C	MIN.	0.2		V
I _H (2)	I _{OUT} = 500 mA		25 °C	MAX.	30	50	mA
١L	I _G = 1.2 x I _{GT}	- -	25 °C	MAX.	50	70	mA
dV/dt ⁽²⁾	V _{OUT} = 67 % V _{DRM} , gate open		125 °C	MIN.	200	2000	V/µs
(dl/dt)c ⁽²⁾	(dV/dt)c = 15 V/µs		125 °C	MIN.	4.4		A/ms
	Without snubber		125 0	IVIIIN.		12	AVIIIS
V _{CL}	$I_{CL} = 0.1 \text{ mA}, t_p = 1 \text{ ms}$		25 °C	MIN.	8	50	V

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max

2. For both polarities of OUT pin referenced to COM pin



Symbol	Test conditi	Test conditions			Unit
V _{TM} ⁽¹⁾	I _{OUT} = 14.1 A, t _p = 500 μs	T _j = 25 °C	MAX.	1.5	V
V _{T0} ⁽¹⁾	Threshold voltage	T _j = 125 °C	MAX.	0.9	V
$R_d^{(1)}$	Dynamic resistance	T _j = 125 °C	MAX.	35	mΩ
I _{DRM}	V _{OUT} = V _{DBM} / V _{BBM}	T _j = 25 °C	MAX.	20	μA
I _{RRM}	VOUT – VDRM/ VRRM	T _j = 125 °C	MAX.	1.2	mA

 Table 4.
 Static characteristics

1. For both polarities of OUT pin referenced to COM pin

Table 5.Thermal characteristics

Symbol	Parameter		Value	Unit
D	Junction to case (AC)	TO-220AB	1.7	°C/W
R _{th(j-c)}	Sufficient to case (AC)	TO-220FPAB	3.5	°C/W
R _{th(j-a)}	Junction to ambient	TO-220AB TO-220FPAB	60	°C/W



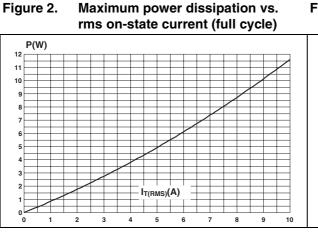


Figure 3. On-state rms current vs. case temperature (full cycle)

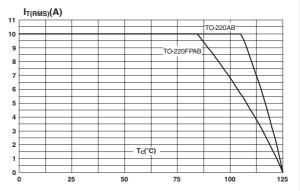


Figure 4. On-state rms current vs. ambient Figure 5. temperature (free air convection full cycle)

Relative variation of thermal impedance vs. pulse duration

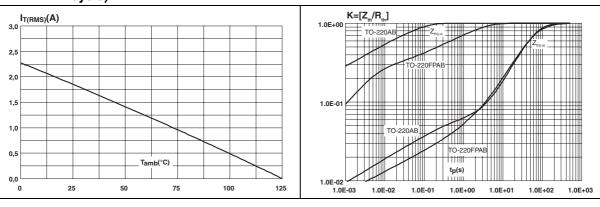
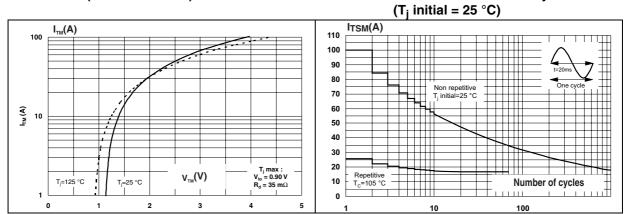
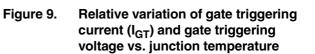


Figure 6. On-state characteristics (maximal values)

Figure 7. Non repetitive surge peak on-state current vs. number of cycles



Non repetitive surge peak on-state Figure 8. current for a sinusoidal pulse and corresponding value of I²t



 $I_{et}, V_{gt}, [T/I_{et}] = 25 \ ^{\circ}C]$

..Q3

-V_{gT}Q1-Q2-Q3

-25

01-0

3.0

2.5

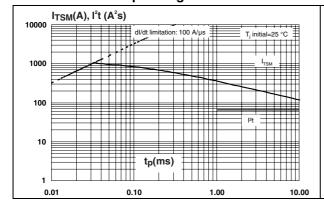
2.0

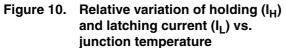
1.5

1.0

0.5

0.0 └─ -50





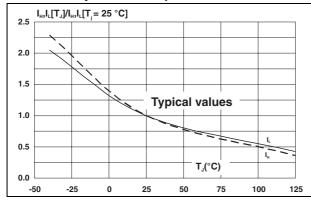
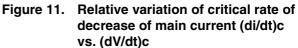


Figure 12. decrease of main current (di/dt)c vs. junction temperature



50

75

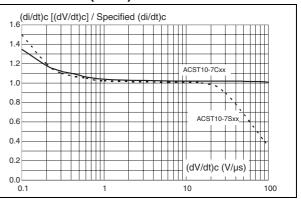
100

125

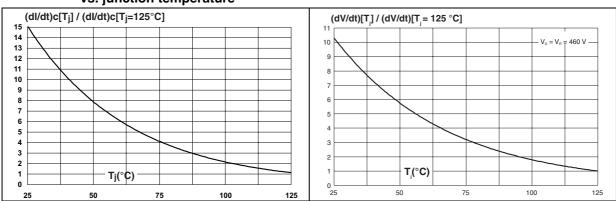
T_.(°C)

25

0



Relative variation of critical rate of Figure 13. Relative variation of static dV/dt vs. junction temperature



5	
	$V_{cL}[T] / V_{cL}[T] = 25 \text{ °C}$
	1.10
	1.05
	1.00 Minimum values
	0.95
	0.90 t _i t _i (°C)
	0.85 -50 -25 0 25 50 75 100 125

Figure 14. Relative variation of maximum clamping voltage, V_{CL} vs. junction temperature

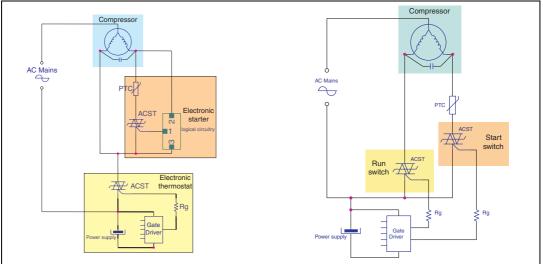


2 Application information

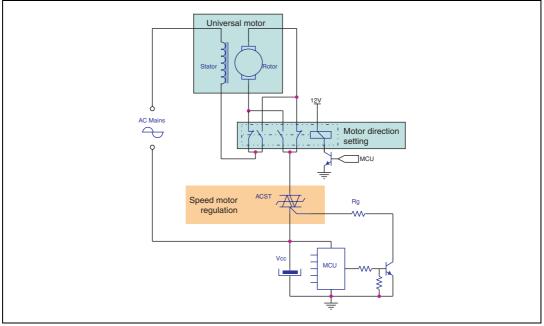
2.1 Typical application description

The ACST10 device has been designed to control medium power load, such as AC motors in home appliances. Thanks to its thermal and turn off commutation performances, the ACST10 switch is able to drive, with no turn off additional snubber, an inductive load up to 10 A. It also provides high thermal performances in static and transient modes such as the compressor inrush current or high torque operating conditions of an AC motor. Thanks to its low gate triggering current level, the ACST10-7S can be driven directly by an MCU through a simple gate resistor as shown *Figure 15*.

Figure 15. Compressor control – typical diagram







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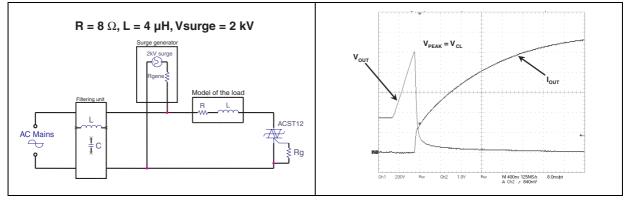
2.2 AC line transient voltage ruggedness

In comparison with standard TRIACs, which are not robust against surge voltage, the ACST10 is self-protected against over-voltage, specified by the new parameter V_{CI} . The ACST10 switch can safely withstand AC line transient voltages either by clamping the low energy spikes or by switching to the on state (for less than 10 ms) to dissipate higher energy shocks through the load. This safety feature works even with high turn-on current rises.

The test circuit of Figure 17 represents the ACST10 application, and is used to stress the ACST switch according to the IEC 61000-4-5 standard conditions. Thanks to the load which is limiting the current, the ACST switch withstands the voltage spikes up to 2 kV above the peak line voltage. The protection is based on an overvoltage crowbar technology. The ACST10 switches safely to the on state as shown in *Figure 18*. The ACST10 recovers its blocking voltage capability after the surge. Such a non repetitive test can be done at least 10 times on each AC line voltage polarity.

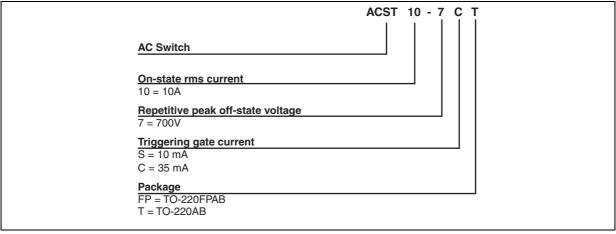
Figure 17. Overvoltage ruggedness test circuit Figure 18. Typical current and voltage for resistive and inductive loads for IEC 61000-4-5 standards

waveforms across the ACST10 during IEC 61000-4-5 standard test



Ordering information scheme 3

Figure 19.	Ordering	information	scheme
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4 Package information

- Epoxy meets UL94, V0
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at *www.st.com*.

Table 6. TO-220AB dimensions

			Dimer	nsions	
	Ref.	Millin	neters	Inches	
		Min.	Max.	Min.	Max.
	А	4.40	4.60	0.173	0.181
	С	1.23	1.32	0.048	0.051
H2 A Dia C.	D	2.40	2.72	0.094	0.107
	E	0.49	0.70	0.019	0.027
	F	0.61	0.88	0.024	0.034
	F1	1.14	1.70	0.044	0.066
	F2	1.14	1.70	0.044	0.066
	G	4.95	5.15	0.194	0.202
$ \downarrow \underbrace{F1}_{H} \underbrace{F1}_{H} \underbrace{P1}_{H} \underbrace$	G1	2.40	2.70	0.094	0.106
L4	H2	10	10.40	0.393	0.409
F→←	L2	16.4	l typ.	0.64	5 typ.
	L4	13	14	0.511	0.551
	L5	2.65	2.95	0.104	0.116
G	L6	15.25	15.75	0.600	0.620
	L7	6.20	6.60	0.244	0.259
	L9	3.50	3.93	0.137	0.154
	М	2.6	typ.	0.102	2 typ.
	Diam.	3.75	3.85	0.147	0.151

			Dimer	nsions	
	Ref.	Millin	neters	Inches	
		Min.	Max.	Min.	Max.
	А	4.4	4.6	0.173	0.181
	В	2.5	2.7	0.098	0.106
H B	D	2.5	2.75	0.098	0.108
	Е	0.45	0.70	0.018	0.027
Dia	F	0.75	1	0.030	0.039
	F1	1.15	1.50	0.045	0.059
L2 L7	F2	1.15	1.50	0.045	0.059
	G	4.95	5.20	0.195	0.205
	G1	2.4	2.7	0.094	0.106
$\int \int \frac{D}{1+e^{-F_1}} \frac{D}{1+e^{-F_1}}$	Н	10	10.4	0.393	0.409
L4 → ← <u>F2</u>	L2	16	Тур.	0.63	Тур.
↓↓₩₩₽ │_│→₩₽₽ ↓	L3	28.6	30.6	1.126	1.205
	L4	9.8	10.6	0.386	0.417
G	L5	2.9	3.6	0.114	0.142
	L6	15.9	16.4	0.626	0.646
	L7	9.00	9.30	0.354	0.366
	Diam.	3.00	3.20	0.118	0.126

Table 7. TO-220FPAB dimensions



5 Ordering information

Table 8.Ordering information

Order code	Marking	Package	Weight	Base qty	Packing mode
ACST10-7ST	ACST107S	TO-220AB	2.3 g	50	Tube
ACST10-7SFP	AC311073	TO-220FPAB	2.3 g	50	Tube
ACST10-7CT	ACST107C	TO-220AB	2.3 g	50	Tube
ACST10-7CFP	ACSTID/C	TO-220FPAB	2.3 g	50	Tube

6 Revision history

Table 9. Document revision history

Date	Revision	Changes
02-Dec-2008	1	First issue



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